CLAIMS:

- 1. An interleaving method for performing parallel access in a linear and interleaved order to a predetermined number of stored data samples, said method comprising the steps of:
- a) storing data samples in a memory array comprising a plurality of memory devices;
- b) using a first portion of an address of said memory array to address said memory devices;
- c) using a second portion of said address to select at least one memory device to be accessed; and
- d) changing a position of said first portion and said second portion within said address, when an access order is changed between a linear order and an interleaved order.
- 2. A method according to claim 1, further comprising the step of performing a parallel access in a multiplexed manner using said second portion of said address portion as a multiplexing index.
- 3. A method according to claim 1, wherein said second portion of said address corresponds to a predetermined number of most significant bits of said address during a linear access order, and corresponds to a predetermined number of least significant bits of said address during an interleaved access order.
- 4. A method according to claim 3, wherein said first portion of said address corresponds to a remaining number of bits within said address.
- 5. A method according to claim 1, further comprising the step of subjecting said first portion of said address to an interleaving processing during an interleaved access order.

- 6. A method according to claim 1, wherein said first portion of said address comprises ten address bits and said second portion of said address comprises two address bits.
- 7. A method according to claim 1, further comprising the step of generating said first portion of said address by an address counting function.
- 8. An interleaving apparatus for providing parallel access in a linear and interleaved order to a predetermined number of stored data samples, said interleaving apparatus comprising:
- a) a memory array with a plurality of memory devices for storing data samples;
- b) addressing means for addressing said memory devices by applying a first portion of an address to said memory devices and by using a second portion of said address to select at least one memory device to be accessed; and
- c) change means for changing a position of said first portion and said second portion within said address in response to a change between a linear order and interleaved order.
- 9. An apparatus according to claim 8, wherein said memory devices are single-port RAM devices.
- 10. An apparatus according to claim 8, wherein said interleaving apparatus is integrated on a single chip device.
- 11. An apparatus according to claim 8, wherein said addressing means comprises an address counter for generating said first address.
- 12. An apparatus according to claim 11, further comprising interleaving means for converting an output address of said address counter

according to a predetermined interleaving scheme to generate said first portion of said address during an interleaved access order.

- 13. An apparatus according to claim 12, wherein said interleaving means comprises at least one of an address translation table and an address logic.
- 14. An apparatus according to claim 8, wherein said change means comprises a control switch for receiving said address and for switching said first portion and second portion within said address to respective output parts in response to an access order selection signal.
- 15. An apparatus according to claim 8, wherein said interleaving apparatus comprises a turbo interleaver for use in a turbo decoder.
- 16. An interleaving apparatus for providing parallel access in a linear and interleaved order to a predetermined number of stored data samples, said interleaving apparatus comprising:
- a) a memory array with a plurality of memory devices for storing data samples;
- b) an addresser configured to address said memory devices by applying a first portion of an address to said memory device and by using a second portion of said address to select at least one memory device to be accessed; and
- c) a changer configured to change a position of said first portion and said second portion within said address in response to a change between a linear order and an interleaved order.